Speci c heat in the integer quantum Halle ect: An exact diagonalization approach

Sudhansu S.M andal and M uktish A charyya

Department of Physics, Indian Institute of Science, Bangabre-560012, India

and

Condensed Matter Theory Unit, Jawaharlal Nehru Centre for Advanced Scienti c Research, Jakkur, Bangalore-560064, India

Abstract

We have studied the integer quantum Hall e ect at nite temperatures by diagonalizing a single body tight binding model Ham iltonian including A haronov-B ohm phase. We have studied the energy dependence of the speci c heat and the Hall conductivity at a given temperature. The speci c heat shows a sharp peak between two consecutive Hall plateaus. At very low tem peratures, the num erical results of the temperature variations of speci c heat (in the plateau region) are in good agreem ent with the analytical results.

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Present Address: Institute for Theoretical Physics, University of Cologne, 50923 Cologne, Germany

Quantum Halle ect continues to draw considerable interest since its surprised discovery [1] in two dimensional electronic systems at very low temperatures and in the presence of very high magnetic elds. In this phenomenon, the Hall conductivity gets quantized at integer lling factors with the value $e^2 = h$ in high accuracy and the diagonal conductivity vanishes at the same time. A similar phenomenon also occurs at certain fractional lling factors as well [2]. In this paper, however, we are concerned only with the integer quantum Halle ect (IQHE).

The scaling theory [3] predicts that all the states are localized in two dimensions due to disorder potential which respects time reversal symmetry. In the presence of strong magnetic eld, perpendicular to the plane of the system, the electronic energy spectrum of the system shows a series of Landau bands. Since the magnetic eld destroys time reversal symmetry and suppresses back scattering, some of the states appear to be extended at the center of each Landau band. On the other hand, the states away from the center of each band remain localized. The transport properties (electronic conduction) of the system do depend on the distribution of localized and extended states. This distribution of localized and extended states, the H all conductivity remains pinned to a value forming a plateau. The critical transition [4] from one plateau to another occurs when Ferm i level passes through the region of extended states.

On the other hand, the equilibrium properties (say speci c heat) of the system depend simply on the density of states [5,6]. These properties cannot distinguish the localized states from extended states. This is indeed so, as it en erges from our system atic num erical diagonalization study in a lattice model. A greeably, the separation of electronic speci c heat from lattice speci c heat in quantum H all systems, from the experimental data, are extremely di cult. However, the experiments [5,7] are performed in multilayer systems to extract electronic speci c heat.

In this paper, we consider a single body (spinless) tight binding model H am iltonian [8] with random impurities in each site in the presence of a uniform magnetic eld perpendicular

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to the lattice plane. We have calculated the H all conductivity $_{\rm H}$ and the speci c heat C_v at a nite temperature T in a nite lattice. We show the formation of H all plateau and the transition between two plateaus of the H all conductivity by studying the energy variation of the H all conductivity. When the Ferm i level lies between two Landau bands, C_v is exponentially sm all since in such a case the probability of low energy excitation is very sm all. In such a region we nd C_v $(1=T^2)e^{-T}$, where T is the temperature and is a typical interband excitation gap. This behavior of C_v is consistent with the analytical results obtained from the self consistent B om approximation. On the other hand, when Ferm i level lies within a Landau band C_v increases substantially and shows a sharp peak. This peak position of C_v lies between two consecutive H all plateaus. We show analytically that C_v in this region is, in fact, proportional to the density of states at Ferm i energy. C_v re exts the pro le of the density of states. The width of the H all conductivity plateau is larger than that of C_v plateau. This is due to the fact that while the transport properties distinguish between localized and extended states, the equilibrium properties do not.

Single body two dimensional tight binding Ham iltonian is given by

$$H = \bigvee_{\substack{\langle ji \rangle \\ \langle ji \rangle \\ }} e^{ia_{ij}}C_{j}^{Y}C_{j} + hc: + \bigvee_{i}^{X} w_{i}C_{i}^{Y}C_{i}$$
(1)

where C_i^y and C_i are spinless Ferm ionic creation and destruction operators respectively at lattice site i. Here < ij > refers to nearest neighbour hopping, and the hopping parameter is taken to be unity. A uniform magnetic eld B is applied such that it produces a uniform magnetic ux = (hc=e)=M (M integer) per plaquette. When a particle hops from site j to site i, it acquires a phase $a_{ij} = {R_i \atop j} K$ dl, where the vector potential in the Landau gauge is taken to be K = (0; B x). For this choice of gauge, an electron gets nonzero phase while hopping along y direction only. The (diagonal) second term in the Ham iltonian corresponds to random disorder potential at site i with strength w_i varying from W = 2 to W = 2. We have constructed the Ham iltonian (1) by considering the periodic boundary condition. As a result, the energy spectrum becom es M number of Landau bands. Each band contains $L^2=M$ states in a square lattice of size L L. We compute the Hall conductivity $_{\rm H}$ using the Kubo form ula [9]

$$_{\rm H} = \frac{ie^{2}h}{L^{2}} \frac{X}{m} \frac{X}{n \in m} \frac{(f_{\rm n} - f_{\rm m}) < m j_{\rm x} j_{\rm n} > < n j_{\rm y} j_{\rm m} >}{(E_{\rm m} - E_{\rm n})^{2}};$$
(2)

where E_n is the energy of $j_n > -th$ state, and

$$v = (i=h) \int_{j}^{X} C_{j+}^{y} C_{j} e^{ia_{j+},j} C_{j}^{y} C_{j+} e^{ia_{j+},j}$$
(3)

is the velocity operator [10] along direction = (\hat{x} or \hat{y}). And $f_n = 1 = (\exp [(E_n \quad E_F) = k_B T] + 1)$ is the Ferm i function at temperature T with Ferm i energy E_F . The electronic speci c heat per unit area of the system can be computed using the form ula [11]:

$$C_{v} = \frac{1}{L^{2}k_{B}T^{2}} \int_{n}^{X} (E_{n} - E_{F})^{2} f_{n} (1 - f_{n}) :$$
 (4)

Figure 1 shows the energy variations of $_{\rm H}$ and $C_{\rm v}$. These are computed using the form ulae (2(4) for a system of size 12 12, strength of random potential W = 0.5, ux per plaquette = (hc=e)=12, and at sm all tem perature $k_B T = 0.01$. Three distinct IQ HE plateaus, between four lowest Landau bands, at $_{\rm H} = (e^2 = h)$ (= 1;2;3) are shown for $E_F < 0$. It is observed that the higher plateaus are form ed at relatively lower values [12] compared to corresponding integral multiple of e^2 =h. The decrease in the value of quantization is due to the relatively higher values of in purity strength for the form ation of the corresponding plateaus [12]. The transitions between plateaus occur at the centers of the Landau bands. In these transition regions, C_v shows sharp but nite peaks with the width same as the Landau band width. In between the Landau bands, C_{v} is exponentially small since the low energy excitations are the least probable and the plateaus in C_v are also form ed. The widths of plateaus in H are relatively higher than that of the corresponding plateaus in C_v . This is because of the fact that the transport properties (like $_{\rm H}$) are sensitive to extended states or localized states which are form ed at the tail of the Landau bands but the equilibrium properties (like C_v) are insensitive to the nature of the states. This is indeed the case since the expression (4) for the speci c heat does not depend on the characteristics (localized or extended) of the states.

Figure 2 shows the tem perature variation of the speci c heat at two di erent energies corresponding to two di erent plateaus (see Fig.1), keeping other parameters xed. The best tted form of C_v is found to be C_v $(1=T^2)e^{-T}$ which is consistent also with the num erical diagonalization result [13] for fractional quantum H all states. Here is a typical excitation gap which we not to be consistent with the Landau band gaps. The values of for these two curves are found to be alm ost sam e while the prefactors are di erent.

We now analytically evaluate the specic heat at the regions of the plateaus and the transition between the plateaus separately at low tem peratures by using self consistent B om approximation (SCBA) for the impurity potential, and compare those with the numerical results. The density of states of an IQHE system in SCBA [14] is given by

$$() = \frac{1}{2 \frac{2}{2}} \frac{2}{2} \prod_{n=1}^{N} [2 (n_{n})^{2}]^{1-2}; \qquad (5)$$

which is a series of sem icircular bands of radius at Landau levels with energy $_{n} = (n + \frac{1}{2})h!_{c}$. Here $!_{c}$ is the cyclotron frequency and l is the magnetic length of the system . We assume that the broadenning 2 of each Landau level is very small compared to h!_c, i.e., << h!_c. The electronic speci c heat of the system can be expressed as

$$C_{v} = \frac{1}{k_{\rm B} T^{2}} \int_{0}^{Z_{\rm I}} () (E_{\rm F})^{2} f() [1 f()] d; \qquad (6)$$

where f () = 1=(e^{[(E_F)=k_BT]} + 1) is the Fermi function.

(i) Speci c heat at the plateau regions: The speci c heat can be expressed using eqns (5) and (6) as

$$C_{v} = \frac{C}{k_{B}T^{2}} \int_{n}^{x} \int_{n}^{z} \int_{n}^{n+} (E_{F})^{2} \int_{n}^{h} (E_{F})^{2} \int_{n}^{h} (E_{F})^{2} f(r) \int_{n}^{1} f(r) \int_{n}^{1} f(r) f(r) dr;$$
(7)

with the constant $C = 1 = (21^{2})^{2}$. We now consider that the Fermi energy E_{F} is in between two consecutive Landau bands. In this case an integer number of bands are lied. By Taylor's expansion of eqn (7) in powers of $=h!_{c}$, we obtain

$$C_{v} = \frac{C_{x}^{2}}{k_{B}T^{2}} x_{n} (n = E_{F})^{2} f(n) [1 = f(n)] + O_{x} \frac{2^{\#}}{h!_{c}} : \qquad (8)$$

At low temperatures (h!_c=k_BT >> 1), we perturbatively evaluate C_v with the expansion parameter [15] e^{h!_c=k_BT}. We thus nd

$$C_{v}(T) = \frac{4}{l^{2}k_{B}} E_{F}^{2} + \frac{l_{c}^{2}N^{2}}{4} E_{F} l_{c}N \frac{\#}{T^{2}} e^{h!_{c}=2k_{B}T}; \qquad (9)$$

where N is the number of led Landau bands. Note that the speci c heat is activated through the gap between two Landau levels. Interestingly, this is the same temperature dependent form of C_v that we have found from our numerical diagonalization study. The prefactor in Eqn (9) depends on the value of Ferm i energy and the number of led Landau bands. For this reason, we obtain two di erent curves for two di erent Ferm i energies in Fig. 2.

(ii) Speci c heat at the regions of transition between two consecutive plateaus: In these regions, Ferm i energy lies inside a Landau band. The approximations made in (i) will not hold good in this case since closeby states above the Ferm i energy are available for low energy excitations. Using Sommerfeld's low temperature expansion [9] of the energy derivative of Ferm i function in eqn (6), we obtain

$$C_v = \frac{2}{3}k_B^2 T$$
 (E_F): (10)

C barly, the speci c heat in the transition regions follows the prode of the density of states which has maxim a at the centers of the Landau bands. This is indeed so that we have also obtained this type of prode from our numerical study. However, the linear temperature dependence that we have obtained in eqn (10) does not resemble with our numerical calculations. In our numerical study, we have obtained a tted form C_v $(1=T^2)e^{-T}$ here as well, with much less than that in the case when Fermi energy lies between two successive Landau bands. We remark that this tted form, in our numerical study, is a consequence of nite size diagonalization study since in such a case, there always remains small but - nite gap between the states within a Landau band. In other words, the linear tem perature dependence of C_v in eqn (10), obtained from continuum description of the density of states

(Eqn (5)) within a Landau band, cannot be achieved by a nite size diagonalization study. However, we believe that in L ! 1 limit, the linear temperature dependence of C_v may hold good.

In sum mary, we have studied the nite temperature Hall conductivity and the specic heat of an IQ HE system by nite size diagonalization of a tight binding model Ham iltonian including A haronov-Bohm phase. The energy variation of Hall conductivity and the specic heat have been studied at low temperatures. The specic heat also shows plateau together with the Hall conductivity, and gets sharply peaked between two consecutive plateaus. We have also calculated specic heat analytically in self consistent Bom approximation. The temperature variation of specic heat (in the plateau region) agrees well with the num erical results.

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Figure Captions

Fig. 1: Energy variations of $_{\rm H}$ (circles) and $C_{\rm v}$ (triangles), for $k_{\rm B}T = 0.01$, W = 0.5 and M = 12. $_{\rm H}$ is shown in the unit e²=h while $C_{\rm v}$ is in arbitrary unit.

Fig. 2: Tem perature variations of C_v for two di erent energies corresponding to two di erent plateaus. (i) C incles represent $E_F = 3.0$ and (ii) Triangles represent $E_F = 2.2$. Solid lines represent the best tted functional form C_v (1=T²)e^{=T}. Here W = 0.5 and M = 12. Here, C_v is shown in arbitrary unit.





